

# **PSMN102-200Y**

# N-channel TrenchMOS SiliconMAX standard level FET Rev. 03 — 16 March 2011 Product de

**Product data sheet** 

#### **Product profile** 1.

#### 1.1 General description

SiliconMAX standard level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product is designed and qualified for use in computing, communications, consumer and industrial applications only.

#### 1.2 Features and benefits

- Higher operating power due to low thermal resistance
- Suitable for high frequency applications due to fast switching characteristics

## 1.3 Applications

- Class D amplifier
- DC-to-DC converters

- Motion control
- Switched-mode power supplies

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DS}$	drain-source voltage	$T_j \ge 25 \text{ °C}; T_j \le 150 \text{ °C}$	-	-	200	V
$I_D$	drain current	$T_{mb} = 25 \text{ °C}; V_{GS} = 10 \text{ V};$ see <u>Figure 1</u> ; see <u>Figure 3</u>	-	-	21.5	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; see <u>Figure 2</u>	-	-	113	W
Static chara	acteristics					
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 12 \text{ A};$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 9}}{\text{see } \frac{\text{Figure 10}}{\text{Figure 10}}};$	-	86	102	mΩ
Dynamic ch	naracteristics					
$Q_{GD}$	gate-drain charge	$V_{GS} = 10 \text{ V}; I_D = 12 \text{ A};$ $V_{DS} = 100 \text{ V}; \text{ see } \underline{\text{Figure 11}};$ $\text{see } \underline{\text{Figure 12}}$	-	10.1	-	nC



# 2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		_
2	S	source	mb	D
3	S	source		
4	G	gate		
mb	D	mounting base; connected to drain	1 2 3 4	mbb076 S
			SOT669 (LFPAK)	

# 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN102-200Y	LFPAK	plastic single-ended surface-mounted package (LFPAK); 4 leads	SOT669

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>j</sub> ≥ 25 °C; T <sub>j</sub> ≤ 150 °C	-	200	V
$V_{DGR}$	drain-gate voltage	$T_j \ge 25$ °C; $T_j \le 150$ °C; $R_{GS} = 20$ kΩ	-	200	V
$V_{GS}$	gate-source voltage		-20	20	V
I <sub>D</sub>	drain current	$V_{GS} = 10 \text{ V}; T_{mb} = 25 \text{ °C}; \text{ see } \frac{\text{Figure 1}}{\text{see } \frac{\text{Figure 3}}{\text{Figure 3}}};$	-	21.5	Α
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; see <u>Figure 1</u>	-	13.6	А
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 \text{ °C}$ ; see Figure 3	-	65	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; see <u>Figure 2</u>	-	113	W
T <sub>stg</sub>	storage temperature		-55	150	°C
Tj	junction temperature		-55	150	°C
Source-drain	diode				
Is	source current	T <sub>mb</sub> = 25 °C	-	52	Α
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$	-	208	Α
Avalanche ru	iggedness				
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	$V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; $I_D$ = 10.8 A; $V_{sup}$ ≤ 200 V; unclamped; $t_p$ = 0.14 ms; $R_{GS}$ = 50 $\Omega$	-	202	mJ

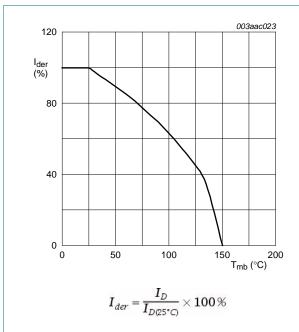


Fig 1. Normalized continuous drain current as a function of mounting base temperature

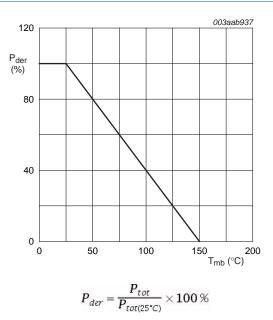


Fig 2. Normalized total power dissipation as a function of solder point temperature

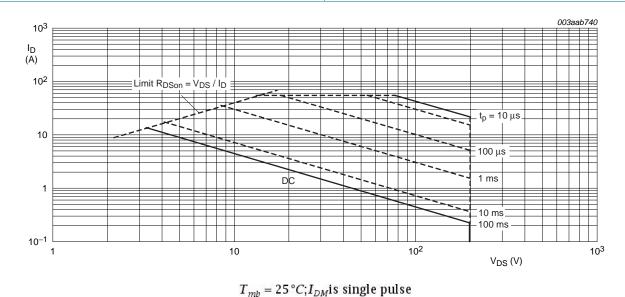
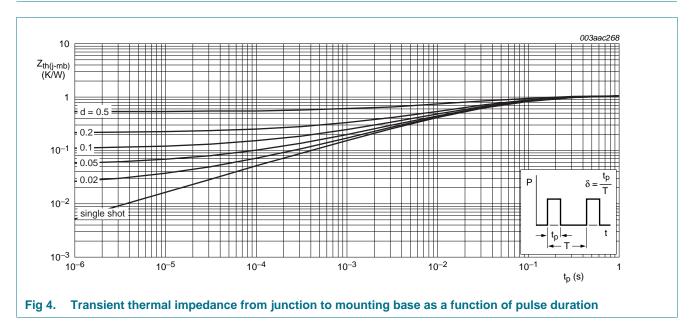


Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Mounted on a printed-circuit board; vertical in still air; see Figure 4	-	-	1.1	K/W



# 6. Characteristics

Table 6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V <sub>(BR)DSS</sub>	drain-source	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	200	-	-	V
	breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$	178	-	-	V
	gate-source threshold voltage	$I_D = 1 \text{ mA}$ ; $V_{DS} = V_{GS}$ ; $T_j = 25 \text{ °C}$ ; see <u>Figure 7</u> ; see <u>Figure 8</u>	2	3	4	V
		$I_D = 1 \text{ mA}$ ; $V_{DS} = V_{GS}$ ; $T_j = 150 \text{ °C}$ ; see <u>Figure 8</u>	1	-	-	V
		$I_D = 1 \text{ mA}$ ; $V_{DS} = V_{GS}$ ; $T_j = -55 \text{ °C}$ ; see <u>Figure 8</u>	-	-	4.4	V
I <sub>DSS</sub>	drain leakage current	$V_{DS} = 160 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	1	μΑ
		$V_{DS} = 160 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$	-	-	100	μΑ
I <sub>GSS</sub>	gate leakage current	$V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 20 \text{ °C}$	-	-	100	nΑ
		$V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 20 \text{ °C}$	-	-	100	nA
Doon	drain-source on-state resistance	$V_{GS} = 10 \text{ V}$ ; $I_D = 12 \text{ A}$ ; $T_j = 25 \text{ °C}$ ; see Figure 9; see Figure 10	-	86	102	mΩ
		$V_{GS} = 10 \text{ V}$ ; $I_D = 12 \text{ A}$ ; $T_j = 150 \text{ °C}$ ; see Figure 9; see Figure 10	-	206	245	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz	-	1.1	-	Ω
Dynamic	characteristics					
Q <sub>G(tot)</sub>	total gate charge	$I_D = 12 \text{ A}; V_{DS} = 100 \text{ V}; V_{GS} = 10 \text{ V};$	-	30.7	-	nC
Q <sub>GS</sub>	gate-source charge	see Figure 11; see Figure 12	-	6.3	-	nC
$Q_{GD}$	gate-drain charge		-	10.1	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	$I_D = 12 \text{ A}$ ; $V_{DS} = 100 \text{ V}$ ; see <u>Figure 11</u> ; see <u>Figure 12</u>	-	4.6	-	V
C <sub>iss</sub>	input capacitance	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$	-	1568	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; see <u>Figure 13</u>	-	170	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	55	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS} = 100 \text{ V}; R_L = 5.8 \Omega; V_{GS} = 10 \text{ V};$	-	14.2	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5.6 \Omega$	-	29.5	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	33	-	ns
t <sub>f</sub>	fall time		-	28	-	ns
Source-d	rain diode					
$V_{SD}$	source-drain voltage	$I_S = 12 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C};$ see Figure 14	-	0.9	1.2	V
t <sub>rr</sub>	reverse recovery time	$I_S$ = 20 A; $dI_S/dt$ = -100 A/ $\mu$ s; $V_{GS}$ = 0 V; $V_{DS}$ = 30 V	-	143	-	ns
Qr	recovered charge	$I_S = 20 \text{ A}$ ; $dI_S/dt = -100 \text{ A/}\mu\text{s}$ ; $V_{GS} = 0 \text{ V}$	-	268	-	nC

50

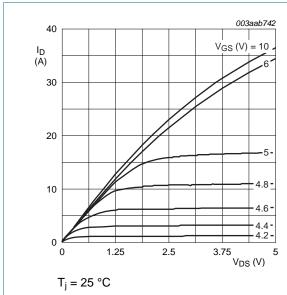


Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values

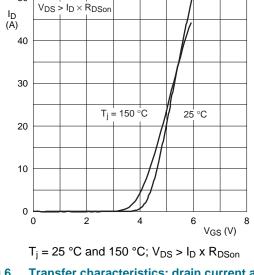


Fig 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values

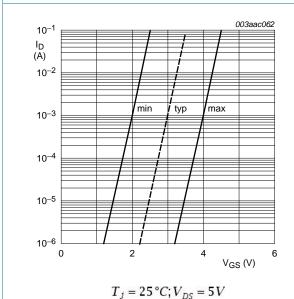


Fig 7. Sub-threshold drain current as a function of gate-source voltage

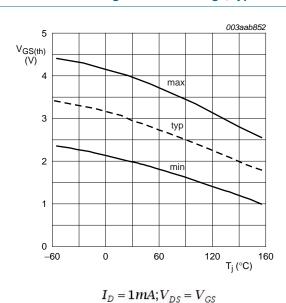


Fig 8. Gate-source threshold voltage as a function of junction temperature

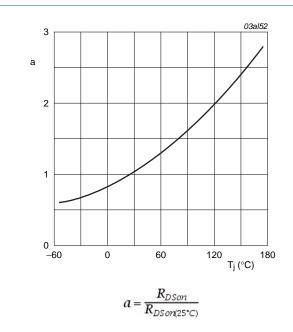


Fig 9. Normalized drain-source on-state resistance factor as a function of junction temperature

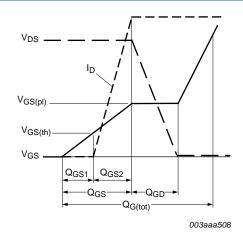


Fig 11. Gate charge waveform definitions

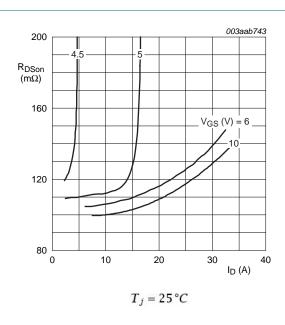
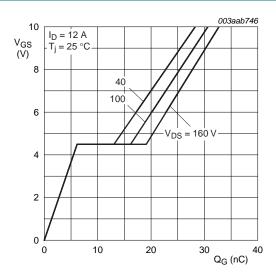


Fig 10. Drain-source on-state resistance as a function of drain current; typical values



 $I_D = 12A; V_{DS} = 40, 100, and 160 V$ 

Fig 12. Gate-source voltage as a function of gate charge; typical values

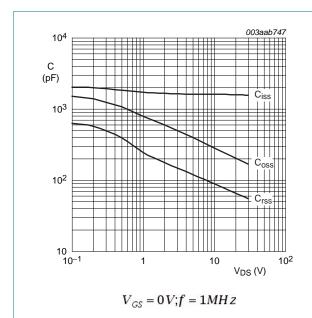


Fig 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

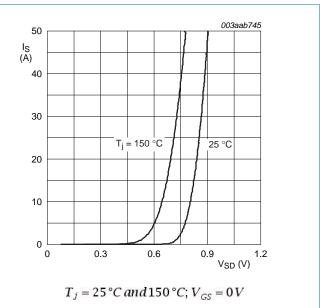


Fig 14. Source current as a function of source-drain voltage; typical values

# Package outline

#### Plastic single-ended surface-mounted package (LFPAK); 4 leads

**SOT669** 

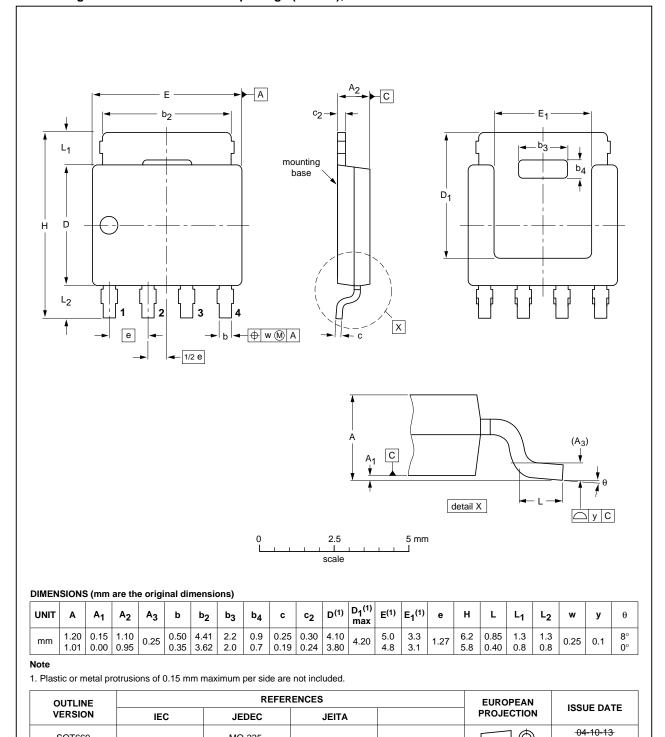


Fig 15. Package outline SOT669 (LFPAK)

PSMN102-200Y

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MO-235

06-03-16

SOT669

# 8. Revision history

#### Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PSMN102-200Y v.3	20110316	Product data sheet	-	PSMN102-200Y v.2
Modifications:	<ul> <li>Various change</li> </ul>	es to content.		
PSMN102-200Y v.2	20101220	Product data sheet	-	PSMN102-200Y v.1

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#### 9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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#### N-channel TrenchMOS SiliconMAX standard level FET

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